





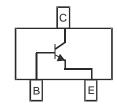
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMBT2907A)
- Ideal for Low Power Amplification and Switching
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe). Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)







Top View

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous	Ic	600	mA
Peak Collector Current	I _{CM}	800	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 1)	P _D	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead. Halogen and Antimony Free.
- No purpose tally added lead. Flatoger and Antimory Free.
 Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic (Note 4)	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	75	_	V	$I_C = 10\mu A, I_E = 0$			
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40	_	V	$I_{C} = 10 \text{mA}, I_{B} = 0$			
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	6.0	_	V	$I_E = 10\mu A, I_C = 0$			
Collector Cutoff Current	I _{CBO}	_	10	nA	$V_{CB} = 60V, I_{E} = 0$			
	iCBO			μΑ	$V_{CB} = 60V, I_E = 0, T_A = 150^{\circ}C$			
Collector Cutoff Current	I _{CEX}	_	10	nA	$V_{CE} = 60V$, $V_{EB(OFF)} = 3.0V$			
Emitter Cutoff Current	I _{EBO}	_	10	nA	$V_{EB} = 3.0V, I_C = 0$			
Base Cutoff Current	I _{BL}	_	20	nA	$V_{CE} = 60V$, $V_{EB(OFF)} = 3.0V$			
ON CHARACTERISTICS (Note 4)	1				1			
		35	_		$I_C = 100 \mu A, V_{CE} = 10 V$			
		50	_		$I_C = 1.0 \text{mA}, V_{CE} = 10 \text{V}$			
		75	_		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}$			
DC Current Gain	h _{FE}	100	300	_	$I_C = 150 \text{mA}, V_{CE} = 10 \text{V}$			
		40	_		$I_C = 500 \text{mA}, V_{CE} = 10 \text{V}$			
		50 35	_		$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}, T_A = -55 ^{\circ}\text{C}$			
		33	_		$I_C = 150 \text{mA}, V_{CE} = 1.0 \text{V}$			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.3	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$			
Concotor Emilior Cataration Voltage	V CE(SAT)		1.0	•	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$			
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$			
	*BE(SAT)		2.0	,	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$			
SMALL SIGNAL CHARACTERISTICS	<u> </u>	1			1			
Output Capacitance	C _{obo}	_	8	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$			
Input Capacitance	C _{ibo}	_	25	pF	$V_{EB} = 0.5V$, $f = 1.0MHz$, $I_C = 0$			
Current Gain-Bandwidth Product	f _T	300	_	MHz	$V_{CE} = 20V$, $I_C = 20mA$, f = 100MHz			
Noise Figure	NF	_	4.0	dB	$V_{CE} = 10V, I_{C} = 100\mu A,$ $R_{S} = 1.0k\Omega, f = 1.0kHz$			
SWITCHING CHARACTERISTICS	•	I		l	,			
Delay Time			10	ns	$V_{CC} = 30V, I_C = 150mA,$			
Delay Time	t _d	_	10	ns	$V_{BE(off)} = -0.5V, I_{B1} = 15mA$			
Rise Time	t _r		25	ns	$V_{CC} = 3.0V$, $I_C = 150mA$, $I_{B1} = 15mA$,			
Trise Time	ιŗ		2.5	119	$V_{BE(OFF)} = 0.5V$			
Storage Time	ts		225	ns	$V_{CC} = 30V, I_C = 150mA,$			
	ıs		220	113	$I_{B1} = I_{B2} = 15\text{mA}$			
Fall Time	t _f		60	ns	$V_{CC} = 30V$, $I_C = 150mA$, $I_{B1} = I_{B2} = 15mA$			

Notes: 4. Short duration pulse test used to minimize self-heating effect.

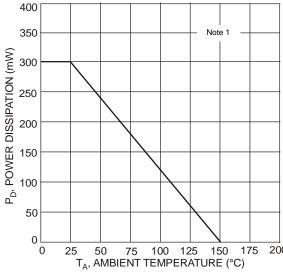


Fig. 1 Power Dissipation vs. Ambient Temperature

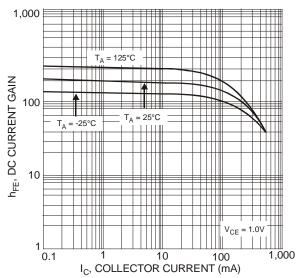


Fig. 2 Typical DC Current Gain vs. Collector Current



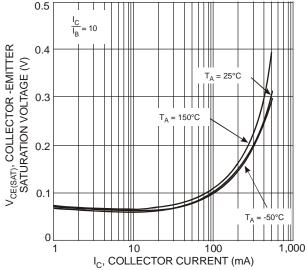


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

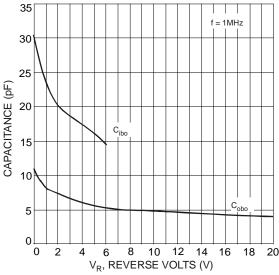


Fig. 5 Typical Capacitance Characteristics

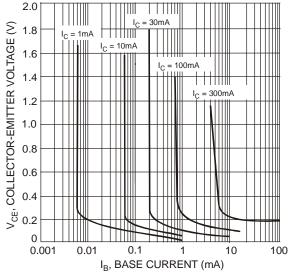
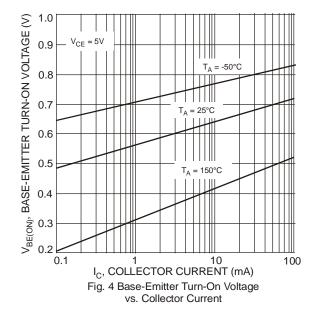
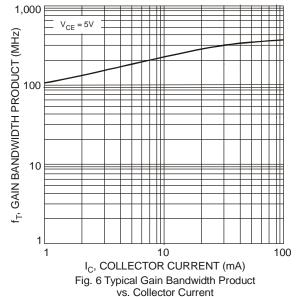


Fig. 7 Typical Collector Saturation Region





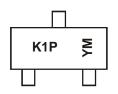


Ordering Information (Note 5)

Part Number	Case	Packaging
MMBT2222A-7-F	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K1P = Product Type Marking Code

YM = Date Code Marking

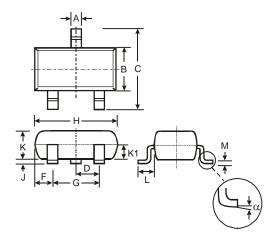
Y = Year (ex: N = 2002)

M = Month (ex: 9 = September)

Date Code Key

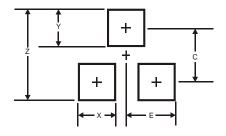
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	J	K	L	М	Ν	Р	R	S	Т	U	V	W	Χ	Υ	Z	Α	В	С
Month	Jan	1	Feb	Mar		Apr	May	/	Jun	Jul		Aug	Sep	1	Oct	Nov	,	Dec

Package Outline Dimensions



SOT-23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
M	0.085	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
ш	1.35

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